

PDFN56

Pin Definition:

- | | |
|-----------|----------|
| 1. Source | 8. Drain |
| 2. Source | 7. Drain |
| 3. Source | 6. Drain |
| 4. Gate | 5. Drain |

Note:

MSL 1 (Moisture Sensitivity Level)
per J-STD-020

TSM055N03PQ56

30V N-Channel MOSFET

Key Parameter Performance

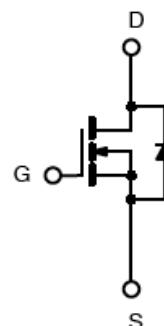
Parameter	Value	Unit
V_{DS}	30	V
$R_{DS(on)}$ (max)	$V_{GS} = 10V$	mΩ
	$V_{GS} = 4.5V$	
Q_g	11.1	nC

Ordering Information

Part No.	Package	Packing
TSM055N03PQ56 RLG	PDFN56	2.5kpcs / 13" Reel

Note: Halogen-free according to IEC 61249-2-21 definition

Block Diagram



N-Channel MOSFET

Absolute Maximum Ratings ($T_c=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	30	V
Gate-Source Voltage	V_{GS}	+20	V
Continuous Drain Current	I_D	80	A
		51	
Drain Current-Pulsed ^(Note 1)	I_{DM}	320	A
Single Pulse Avalanche Energy ^(Note 2)	E_{AS}	88	mJ
Maximum Power Dissipation @ $T_c = 25^\circ\text{C}$	P_D	74	W
Storage Temperature Range	T_{STG}	-55 to +150	°C
Operating Junction Temperature Range	T_J	-55 to +150	°C

Thermal Performance

Parameter	Symbol	Limit	Unit
Thermal Resistance - Junction to Case	$R_{\Theta JC}$	1.7	°C/W
Thermal Resistance - Junction to Ambient	$R_{\Theta JA}$	62	°C/W

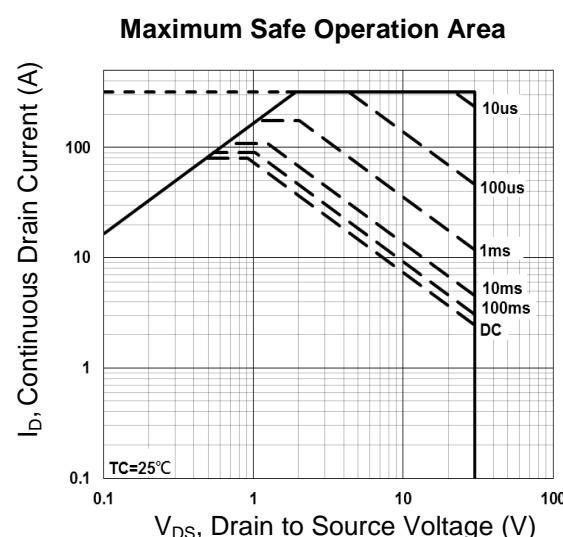
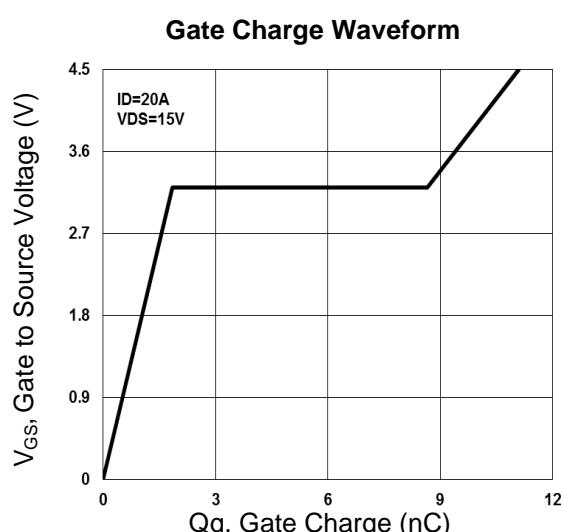
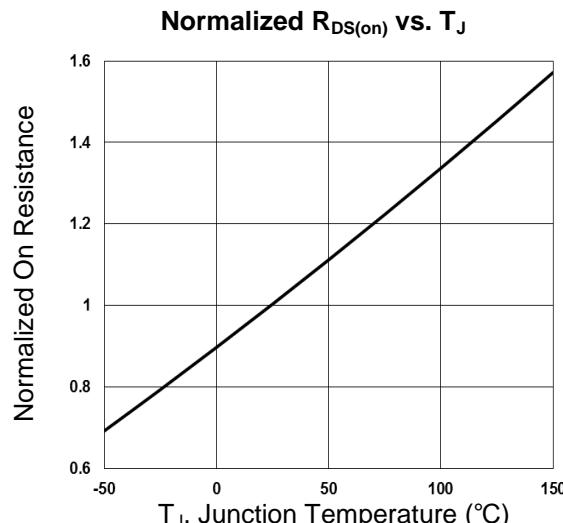
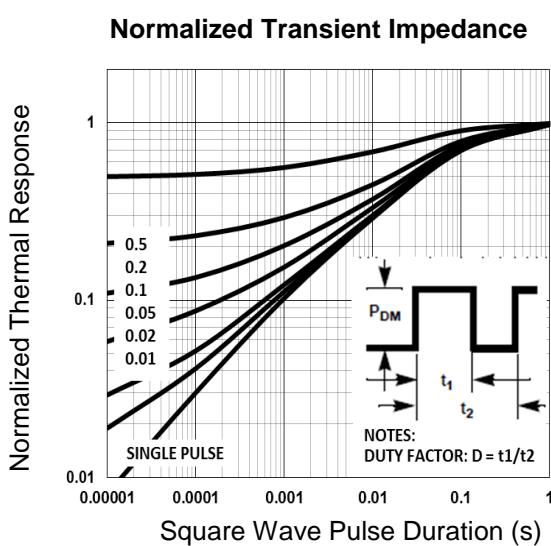
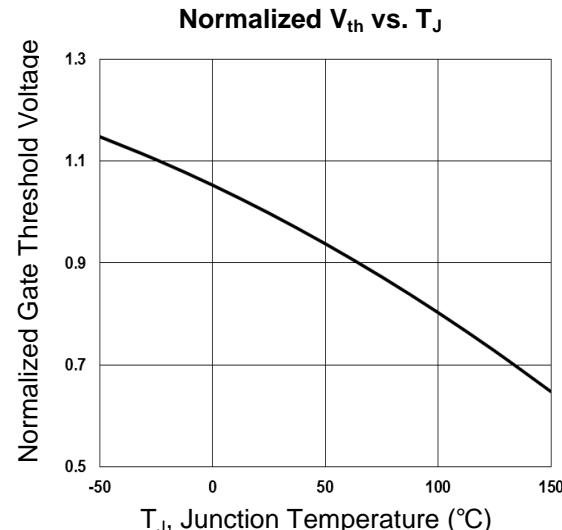
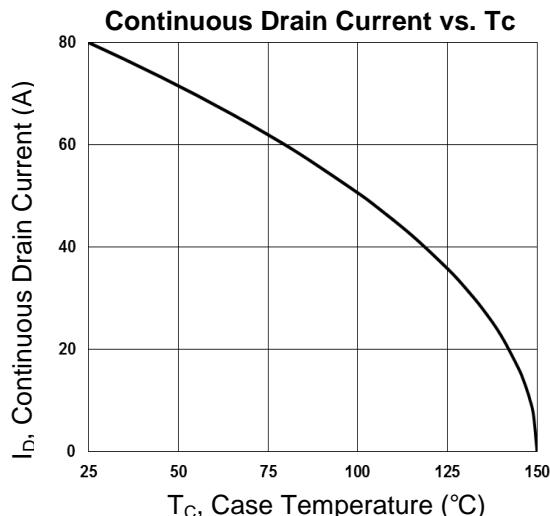
Electrical Specifications ($T_C = 25^\circ\text{C}$ unless otherwise noted)

Parameter	Conditions	Symbol	Min	Typ	Max	Unit
Static						
Drain-Source Breakdown Voltage	$V_{GS} = 0\text{V}, I_D = 250\mu\text{A}$	BV_{DSS}	30	--	--	V
Drain-Source On-State Resistance	$V_{GS} = 10\text{V}, I_D = 20\text{A}$	$R_{DS(\text{ON})}$	--	4.5	5.5	$\text{m}\Omega$
	$V_{GS} = 4.5\text{V}, I_D = 10\text{A}$			6.3	8.5	
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250\mu\text{A}$	$V_{GS(\text{TH})}$	1.2	1.6	2.5	V
Zero Gate Voltage Drain Current	$V_{DS} = 30\text{V}, V_{GS} = 0\text{V}$	I_{DSS}	--	--	1	μA
	$V_{DS} = 24\text{V}, V_{GS} = 0\text{V}, T_J = 125^\circ\text{C}$		--	--	10	μA
Gate Body Leakage	$V_{GS} = \pm 20\text{V}, V_{DS} = 0\text{V}$	I_{GSS}	--	--	± 100	nA
Dynamic						
Total Gate Charge ^(Note 3,4)	$V_{DS} = 15\text{V}, I_D = 20\text{A}, V_{GS} = 4.5\text{V}$	Q_g	--	11.1	--	nC
Gate-Source Charge ^(Note 3,4)		Q_{gs}	--	1.85	--	
Gate-Drain Charge ^(Note 3,4)		Q_{gd}	--	6.8	--	
Input Capacitance	$V_{DS} = 25\text{V}, V_{GS} = 0\text{V}, f = 1.0\text{MHz}$	C_{iss}	--	1160	--	pF
Output Capacitance		C_{oss}	--	200	--	
Reverse Transfer Capacitance		C_{rss}	--	180	--	
Switching						
Turn-On Delay Time ^(Note 3,4)	$V_{GS} = 10\text{V}, V_{DS} = 15\text{V}, R_G = 3.3\Omega, I_D = 15\text{A}$	$t_{d(on)}$	--	7.5	--	ns
Turn-On Rise Time ^(Note 3,4)		t_r	--	14.5	--	
Turn-Off Delay Time ^(Note 3,4)		$t_{d(off)}$	--	35.2	--	
Turn-Off Fall Time ^(Note 3,4)		t_f	--	9.6	--	
Drain-Source Diode Characteristics and Maximum Rating						
Maximum Continuous Drain-Source Diode Forward Current	Integral reverse diode in the MOSFET	I_S	--	--	80	A
Maximum Pulse Drain-Source Diode Forward Current		I_{SM}	--	--	320	A
Drain-Source Diode Forward Voltage	$V_{GS} = 0\text{V}, I_S = 1\text{A}$	V_{SD}	--	--	1	V

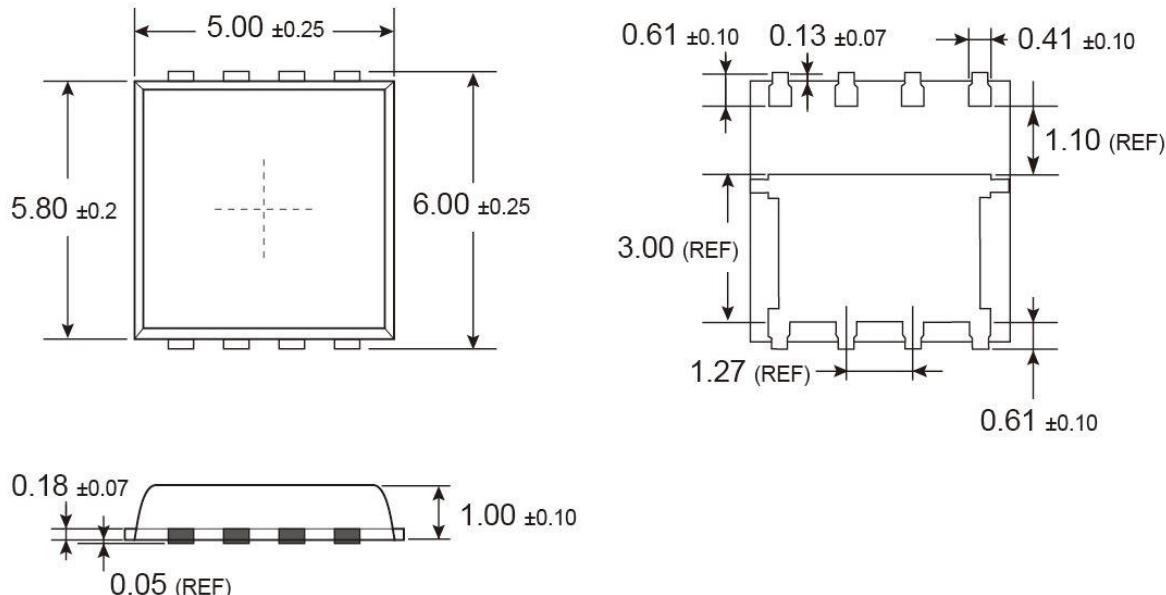
Notes:

1. Repetitive Rating : Pulsed width limited by maximum junction temperature.
2. $V_{DD} = 25\text{V}, V_{GS} = 10\text{V}, L = 0.1\text{mH}, I_{AS} = 42\text{A}, R_G = 25\Omega$, Starting $T_J = 25^\circ\text{C}$.
3. Pulse test: pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$
4. Essentially independent of operating temperature.

Electrical Characteristics Curves



PDFN56 Mechanical Drawing



Unit: Millimeters

Marking Diagram



- Y** = Year Code
- M** = Month Code for Halogen Free Product
 (O=Jan, P=Feb, Q=Mar, R=Apl, S=May, T=Jun, U=Jul, V=Aug, W=Sep,
 X=Oct, Y=Nov, Z=Dec)
- L** = Lot Code

Notice

Specifications of the products displayed herein are subject to change without notice. TSC or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, to any intellectual property rights is granted by this document. Except as provided in TSC's terms and conditions of sale for such products, TSC assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of TSC products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify TSC for any damages resulting from such improper use or sale.